

## JAN2N6989

Request a Quote

#### **JAN2N6989 Information**

Heisener.com	Part Number	JAN2N6989
	Manufacturer	Microsemi Corporation
	Category	Discrete Semiconductor Products Transistors - Bipolar (BJT) - Arrays
	Description	TRANS 4NPN 50V 0.8A TO116
	Package	14-DIP (0.300", 7.62mm)
		For the pricing/inventory/lead time, please contact
For Reference Only		us Website: https://www.heisener.com E-mail: salesdept@heisener.com

## **Certified Quality**

Heisener's commitment to quality has shaped our processes for sourcing, testing, shipping, and every step in between. This foundation underlies each component we sell.



## **JAN2N6989 Specifications**

Manufacturer Part Number	JAN2N6989
Manufacturer	Microsemi Corporation
Category	Discrete Semiconductor Products
	Transistors - Bipolar (BJT) - Arrays
Package	14-DIP (0.300", 7.62mm)
Series	Military, MIL-PRF-19500/559
Transistor Type	4 NPN (Quad)
Current - Collector (Ic) (Max)	800mA
Voltage - Collector Emitter Breakdown (Max)	50V
Vce Saturation (Max) @ Ib, Ic	1V @ 50mA, 500mA
Current - Collector Cutoff (Max)	10µA (ICBO)
DC Current Gain (hFE) (Min) @ Ic, Vce	100 @ 150mA, 10V
Power - Max	1.5W
Frequency - Transition	-
Operating Temperature	-65°C ~ 200°C (TJ)
Mounting Type	Through Hole
Package / Case	14-DIP (0.300", 7.62mm)
Supplier Device Package	TO-116
	Report errors?

#### **JAN2N6989 Guarantees**



Quality Guarantees

We provide 90 days warranty. \* If the items you received were not in perfect quality, we would be responsible for your refund or replacement, but the items must be returned in their original condition.

# SERVICE BUARANTEE

#### **Service Guarantees**

We guarantee 100% customer satisfaction. Our experienced sales team and tech support team back our services to satisfy all our customers.



If you have any question about JAN2N6989, please do not hesitate to contact us! Website: https://www.heisener.com E-mail: salesdept@heisener.com